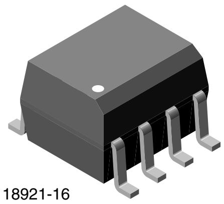
High Speed Optocoupler, 10 MBd, Dual, SOIC-8 Package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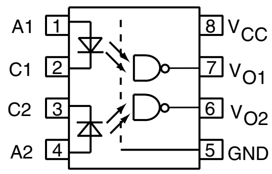

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LINKS TO ADDITIONAL RESOURCES

Related Documents | Design Tools | SPICE Models

DESCRIPTION

The SFH675xT-series, is a dual channel 10 MBd optocoupler utilizing a high efficient input LED coupled with an integrated optical photodiode IC detector. The detector has an open drain NMOS-transister output, providing less leakage compared to an open collector Schottky clamped transister output. The internal shield provides a guaranteed common mode transient immunity of 5 kV/μs for the SFH6756T and 15 kV/μs for the SFH6757T. The use of a 0.1 μF bypass capacitor connected between pin 5 and 8 is recommended.

AGENCY APPROVALS

- UL
- cUL
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1

FEATURES

- Choice of CMR performance of 15 kV/μs, 5 kV/μs, and 100 V/μs
- External creepage distance > 5 mm
- High speed: 10 Mbd typical
- + 5 V CMOS compatibility
- Guaranteed AC and DC performance over temperature: - 40 °C to + 100 °C temperature range
- Pure tin leads
- Meets IEC 60068-2-42 (SO_2) and IEC 60068-2-43 (H_2S) requirements
- Low input current capability: 5 mA
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

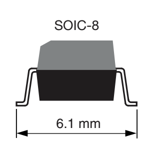
Pb-free
e3
RoHS
COMPLIANT

APPLICATIONS

- Microprocessor system interface
- PLC, ATE input/output isolation
- Computer peripheral interface
- Digital fieldbus isolation: CC-link, DeviceNet, profibus, SDS
- High speed A/D and D/A conversion
- AC plasma display panel level shifting
- Multiplexed data transmission
- Digital control power supply
- Ground loop elimination

ORDERING INFORMATION

S	F	H	6	7	5	#	T
PART NUMBER							TAPE AND REEL



AGENCY CERTIFIED / PACKAGE	CMR (kV/μs)	CMR (kV/μs)	CMR (kV/μs)
UL, cUL	**0.1**	**5**	**15**
SOIC-8	SFH6755T	SFH6756T	SFH6757T

TRUTH TABLE (positive logic)		
LED	**ENABLE**	**OUTPUT**
On	H	L
Off	H	H
On	L	H
Off	L	H
On	NC	L
Off	NC	H

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
INPUT				
Average forward current (single channel)		I_F	20	mA
Average forward current (per channel for dual channel)		I_F	15	mA
Reverse input voltage		V_R	5	V
Surge current	t = 100 μs	I_{FSM}	200	mA
Output power dissipation (single channel)		P_{diss}	35	mW
Output power dissipation (per channel for dual channel)		P_{diss}	25	mW
OUTPUT				
Supply voltage	1 min maximum	V_{CC}	7	V
Output current		I_O	50	mA
Output voltage		V_O	7	V
Output power dissipation (single channel)		P_{diss}	85	mW
Output power dissipation (for dual channel)		P_{diss}	60	mW
COUPLER				
Isolation test voltage	t = 1 s	V_{ISO}	4000	V_{RMS}
Storage temperature		T_{stg}	- 55 to + 150	°C
Operating temperature		T_{amb}	- 40 to + 100	°C
Lead solder temperature	for 10 s		260	°C
Solder reflow temperature [(1)]	for 1 min	T_{sld}	260	°C

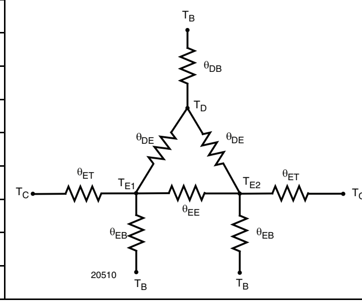
Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

(1) Refer to reflow profile for soldering conditions for surface mounted devices.

RECOMMENDED OPERATING CONDITIONS					
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**MAX.**	**UNIT**
Operating temperature		T_{amb}	- 40	100	°C
Supply voltage		V_{CC}	4.5	5.5	V
Input current low level		I_{FL}	0	250	μA
Input current high level		I_{FH}	5	15	mA
Output pull up resistor		R_L	330	4K	Ω
Fanout	R_L = 1 kΩ	N		5	-

THERMAL CHARACTERISTICS				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
LED power dissipation	at 25 °C	P_{diss}	100	mW
Output power dissipation	at 25 °C	P_{diss}	500	mW
Maximum LED junction temperature		T_{jmax}	125	°C
Maximum output die junction temperature		T_{jmax}	125	°C
Thermal resistance, junction emitter to emitter		θ_{EE}	412	°C/W
Thermal resistance, junction detector to emitter		θ_{DE}	133	°C/W
Thermal resistance, junction emitter to board		θ_{EB}	120	°C/W
Thermal resistance, junction detector to board		θ_{DB}	77	°C/W
Thermal resistance, junction emitter to case		θ_{EC}	110	°C/W



Note

- The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's Thermal Characteristics of Optocouplers application note.

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, and V_{CC} = 5.5 V, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
INPUT						
Input forward voltage	I_F = 10 mA	V_F	1.1	1.4	1.7	V
Reverse current	V_R = 5 V	I_R	-	0.01	10	µA
Input capacitance	f = 1 MHz, V_F = 0 V	C_I	-	55	-	pF
OUTPUT						
High level supply current (single channel)	V_E = 0.5 V, I_F = 0 mA	I_{CCH}	-	4.1	7	mA
	V_E = V_{CC}, I_F = 0 mA	I_{CCH}	-	3.3	6	mA
High level supply current (dual channel)	I_F = 0 mA	I_{CCH}	-	6.5	12	mA
Low level supply current (single channel)	V_E = 0.5 V, I_F = 10 mA	I_{CCL}	-	4	7	mA
	V_E = V_{CC}, I_F = 10 mA	I_{CCL}	-	3.3	6	mA
Low level supply current (dual channel)	I_F = 10 mA	I_{CCL}	-	6.5	12	mA
High level output current	V_E = 2 V, V_O = 5.5 V, I_F = 250 µA	I_{OH}	-	0.002	1	µA
Low level output voltage	V_E = 2 V, I_F = 5 mA, I_{OL} (sinking) = 13 mA	V_{OL}	-	0.2	0.6	V
Input threshold current	V_E = 2 V, V_O = 5.5 V, I_{OL} (sinking) = 13 mA	I_{TH}	-	2.4	5	mA

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

SWITCHING CHARACTERISTICS						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Propagation delay time to high output level	R_L = 350 Ω, C_L = 15 pF	t_{PLH}	20	48	100	ns
Propagation delay time to low output level	R_L = 350 Ω, C_L = 15 pF	t_{PHL}	25	50	100	ns
Pulse width disortion	R_L = 350 Ω, C_L = 15 pF	$\|t_{PHL} - t_{PLH}\|$	-	2.9	35	ns
Propagation delay skew	R_L = 350 Ω, C_L = 15 pF	t_{PSK}	-	8	40	ns
Output rise time (10 to 90 %)	R_L = 350 Ω, C_L = 15 pF	t_r	-	23	-	ns
Output fall time (90 to 10 %)	R_L = 350 Ω, C_L = 15 pF	t_f	-	7	-	ns

Note

- Over recommended temperature (T_A = - 40 °C to + 100 °C), V_{CC} = 5 V, I_F = 7.5 mA unless otherwise specified. All typicals at T_{amb} = 25 °C, V_{CC} = 5 V.

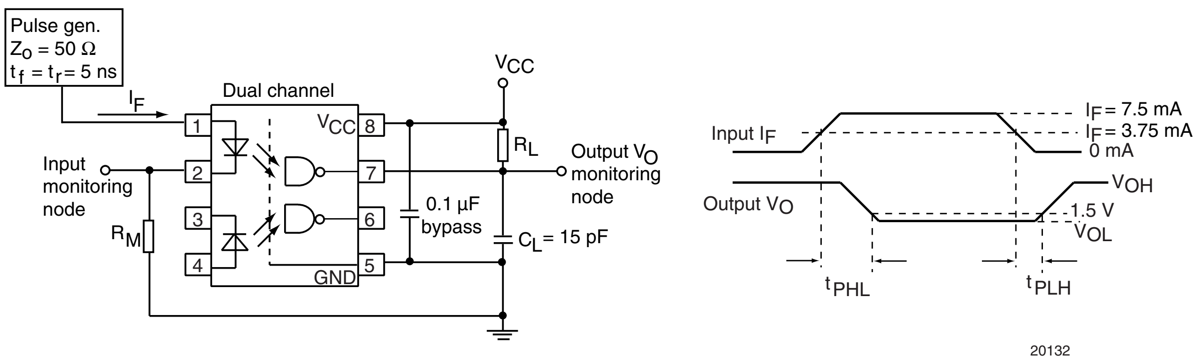


Fig. 1 - Dual Channel Test Circuit for t_{PLH}, t_{PHL}, t_r and t_f

COMMON MODE TRANSIENT IMMUNITY						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Common mode transient immunity (high)	$\|V_{CM}\|$ = 10 V, V_{CC} = 5 V, I_F = 0 mA, $V_{O(min.)}$ = 2 V, R_L = 350 Ω, T_{amb} = 25 °C (1)	$\|CM_H\|$	100	-	-	V/µs
	$\|V_{CM}\|$ = 50 V, V_{CC} = 5 V, I_F = 0 mA, $V_{O(min.)}$ = 2 V, R_L = 350 Ω, T_{amb} = 25 °C (2)	$\|CM_H\|$	5000	10 000	-	V/µs
	$\|V_{CM}\|$ = 1 kV, V_{CC} = 5 V, I_F = 0 mA, $V_{O(min.)}$ = 2 V, R_L = 350 Ω, T_{amb} = 25 °C (3)	$\|CM_H\|$	15 000	25 000	-	V/µs
Common mode transient immunity (low)	$\|V_{CM}\|$ = 10 V, V_{CC} = 5 V, I_F = 7.5 mA, $V_{O(max.)}$ = 0.8 V, R_L = 350 Ω, T_{amb} = 25 °C (1)	$\|CM_L\|$	100	-	-	V/µs
	$\|V_{CM}\|$ = 50 V, V_{CC} = 5 V, I_F = 7.5 mA, $V_{O(max.)}$ = 0.8 V, R_L = 350 Ω, T_{amb} = 25 °C (2)	$\|CM_L\|$	5000	10 000	-	V/µs
	$\|V_{CM}\|$ = 1 kV, V_{CC} = 5 V, I_F = 7.5 mA, $V_{O(max.)}$ = 0.8 V, R_L = 350 Ω, T_{amb} = 25 °C (3)	$\|CM_L\|$	15 000	25 000	-	V/µs

Notes

(1) For SFH6755T
(2) For SFH6756T
(3) For SFH6757T

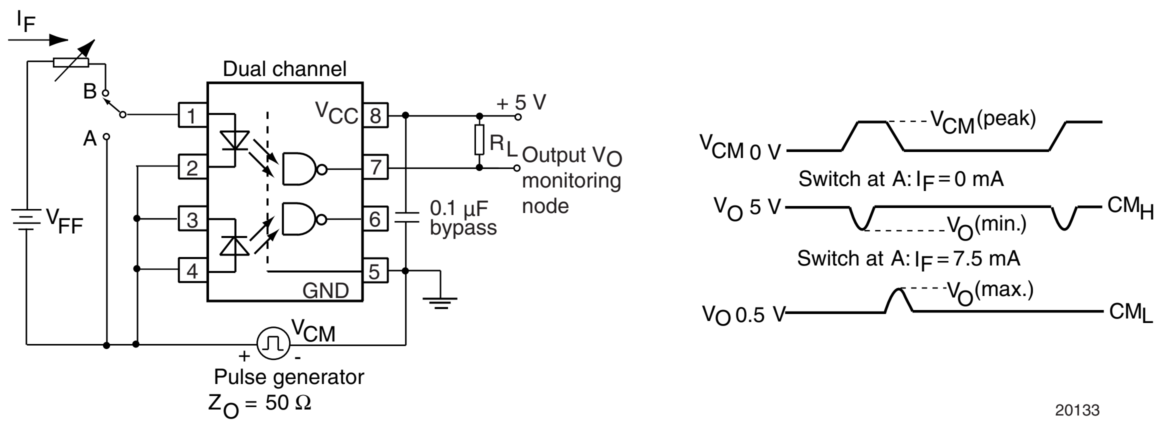


Fig. 2 - Dual Channel Test Circuit for Common Mode Transient Immunity

SAFETY AND INSULATION RATINGS						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Climatic classification	According to IEC 68 part 1			55 / 100 / 21		
Comparative tracking index		CTI	175		399	
Peak transient overvoltage		V_{IOTM}	6000			V
Peak insulation voltage		V_{IORM}	560			V
Safety rating - power output		P_{SO}			350	mW
Safety rating - input current		I_{SI}			150	mA
Safety rating - temperature		T_{SI}			165	°C
Creepage distance			5			mm
Clearance distance			4			mm
Insulation thickness			0.2			mm

Note

- As per IEC 60747-5-5, §7.4.3.8.1, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of prodective circuits.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

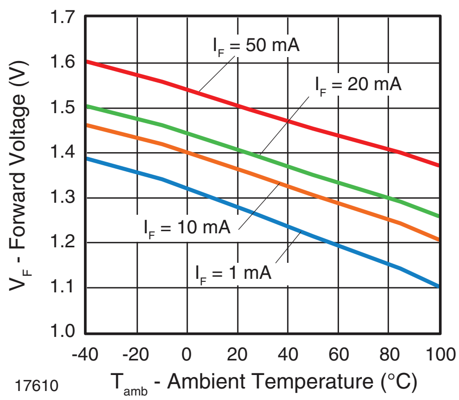


Fig. 3 - Forward Voltage vs. Ambient Temperature

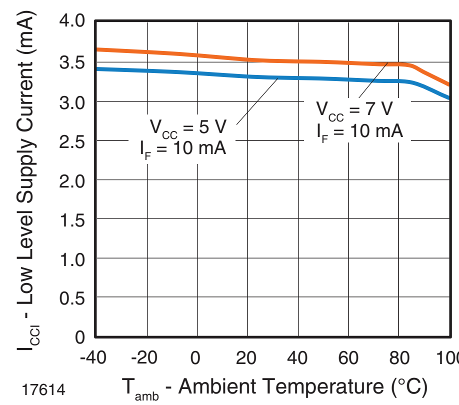


Fig. 6 - Low Level Supply Current vs. Ambient Temperature

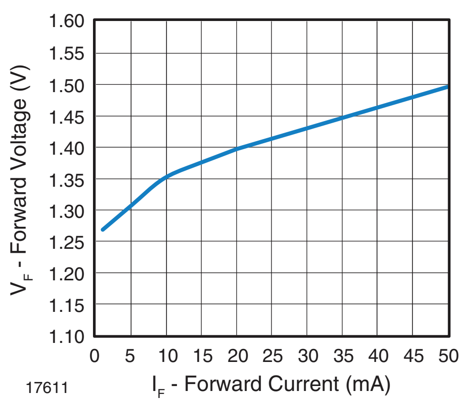


Fig. 4 - Forward Voltage vs. Forward Current

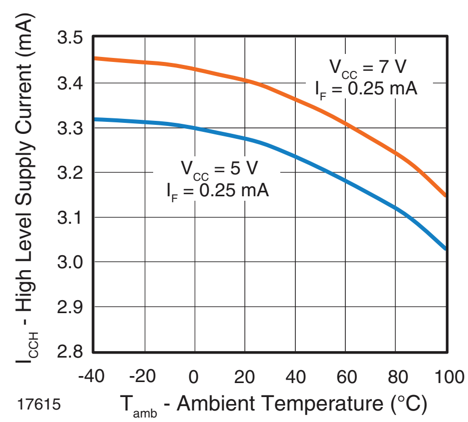


Fig. 7 - High Level Supply Current vs. Ambient Temperature

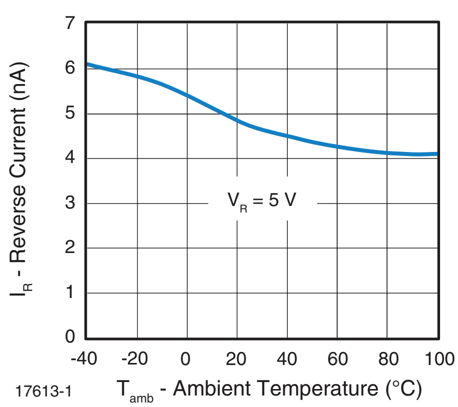


Fig. 5 - Reverse Current vs. Ambient Temperature

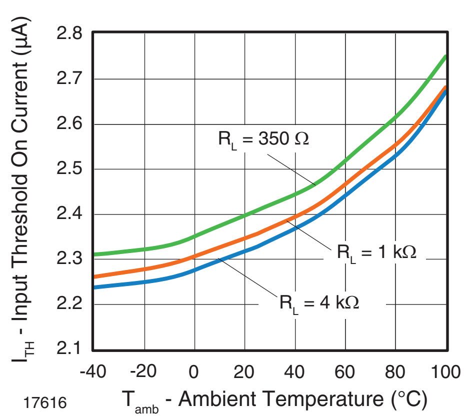


Fig. 8 - Input Threshold on Current vs. Ambient Temperature

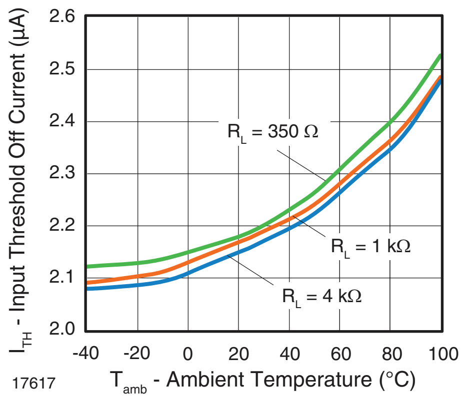


Fig. 9 - Input Threshold off Current vs. Ambient Temperature

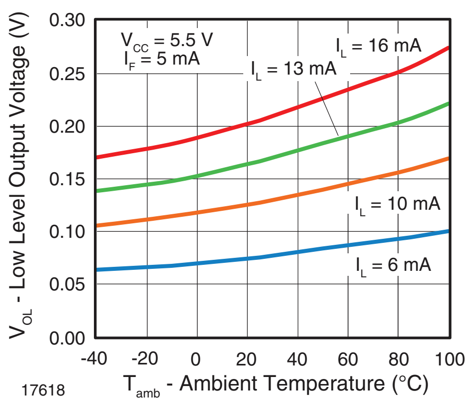


Fig. 10 - Low Level Output Voltage vs. Ambient Temperature

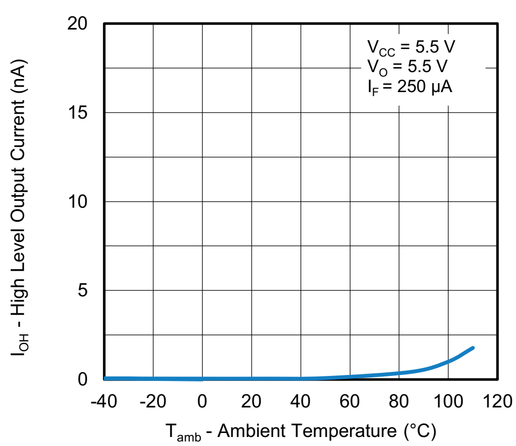


Fig. 11 - Low Level Output Current vs. Ambient Temperature

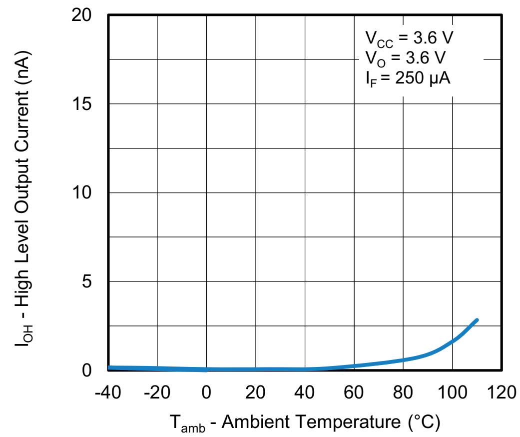


Fig. 12 - High Level Output Current vs. Ambient Temperature

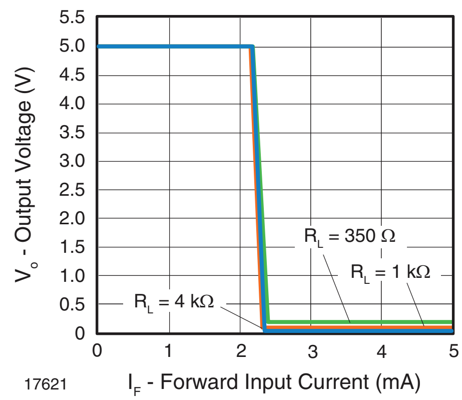


Fig. 13 - Output Voltage vs. Forward Input Current

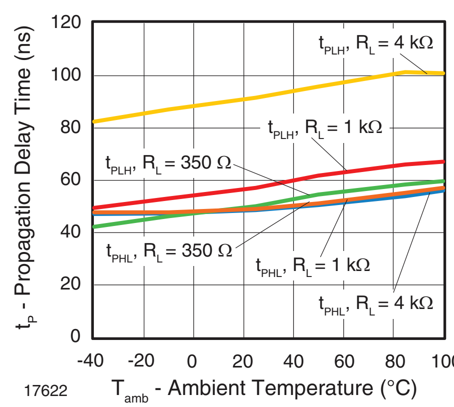


Fig. 14 - Propagation Delay vs. Ambient Temperature

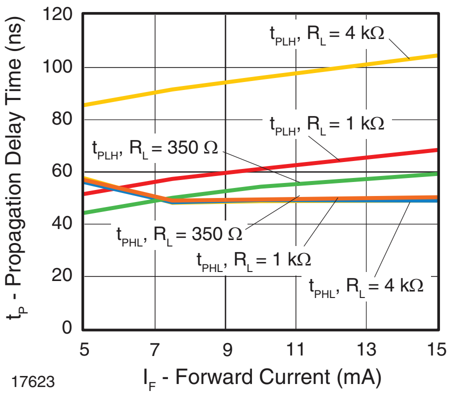


Fig. 15 - Propagation Delay vs. Forward Current

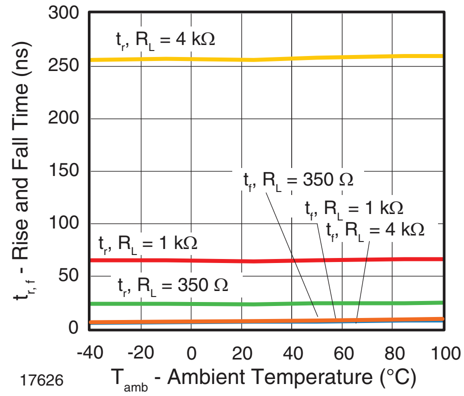


Fig. 18 - Rise and Fall Time vs. Ambient Temperature

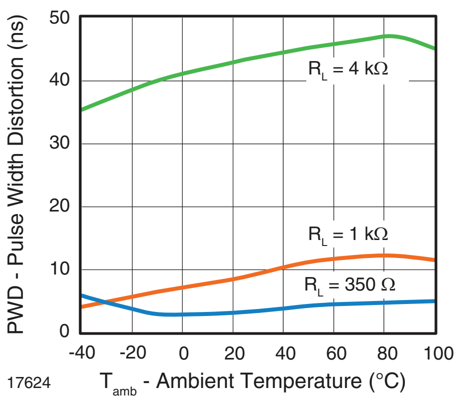


Fig. 16 - Pulse Width Distortion vs. Ambient Temperature

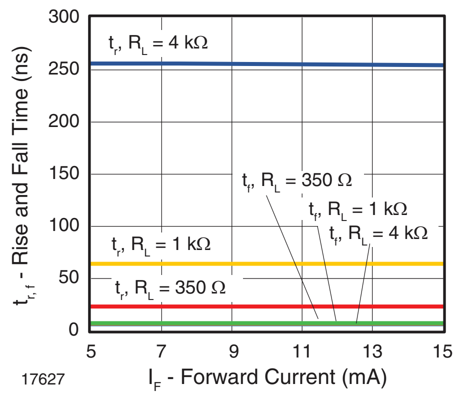


Fig. 19 - Rise and Fall Time vs. Forward Current

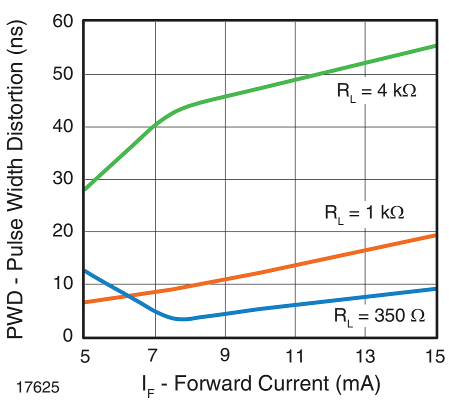
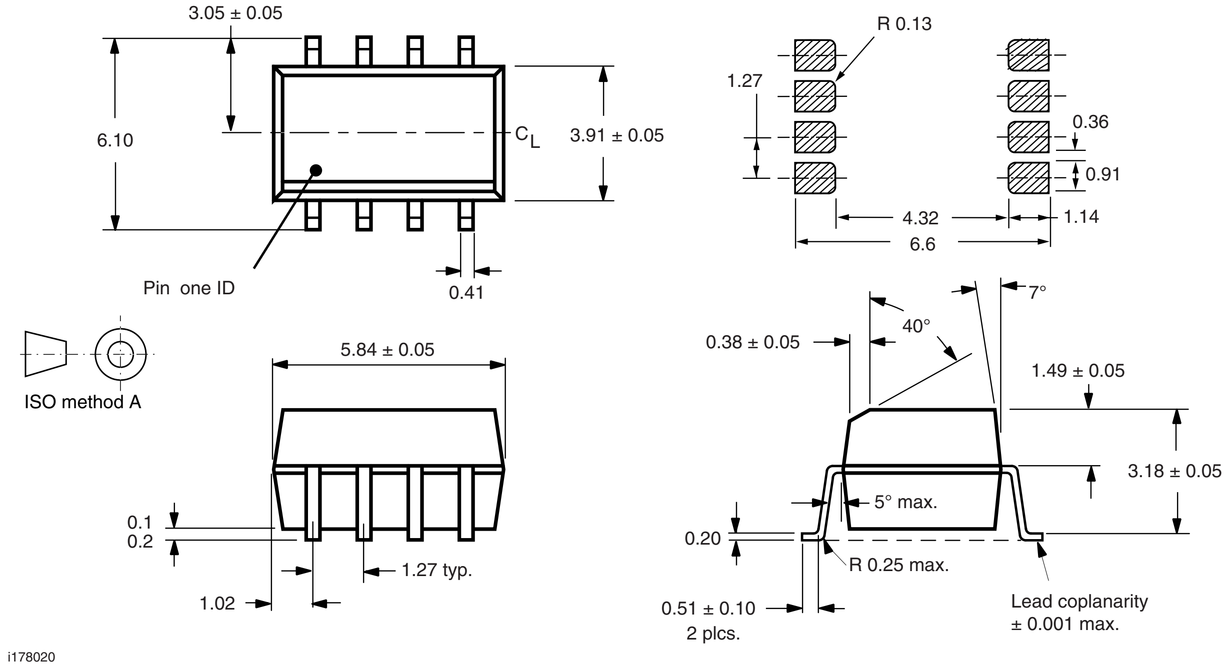


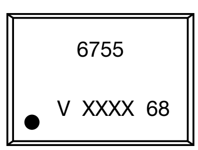
Fig. 17 - Pulse Width Distortion vs. Forward Current

PACKAGE DIMENSIONS in millimeters

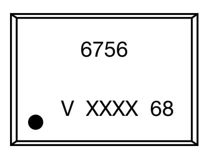
Dual Channel SOIC-8



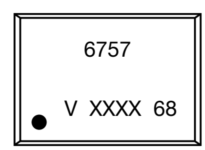
PACKAGE MARKING (example)



Example for SFH6755T



Example for SFH6756T



Example for SFH6757T

Notes

- XXXX = LMC (lot marking code)
- “X1” is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking

ESD CAUTION

This is an ESD (electro static discharge) sensitive device. Electrostatic charges accumulate on the human body and test equipment and can discharge without detection. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality. ESD withstand voltage of this device is up to 1500 V acc. to JESD22-A114-B.

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